

Ab Initio and Multi-Scale Study of Alloy Systems



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AGENDA

- INTRODUCTION
- APPROACH
- **REAXFF DEVELOPMENT**
- **REAXFF MOLECULAR DYNAMIC MODELING**
- QUESTIONS AND DISCUSSION





INTRODUCTION





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- New materials with micro-to-nano features (e.g., grain shape and size distribution, grain boundary character, grain orientation, and texture) are of vital importance for a clean energy economy.
- However, the current trial-and-error material development methodology is expensive (> \$10M) and time consuming (10 to 20 years).
- Activity and excitement over new materials have enhanced, driven by government investment (http://www.whitehouse.gov/blog/2011/06/24/materials-genome-initiative-renaissance-american-manufacturing).
- Increasing trend is to use the advances in multi-scale simulations and high-throughput screening.
- CFD Research Corporation (CFDRC) and Pennsylvania State University (PSU) have teamed in this project to develop, demonstrate, and validate computational capabilities for predictive analysis of interactions at the grain boundary of refractory alloys.





- High-chromia refractories could last ~ 3.5 years in a slagging coal gasifier under optimum conditions (Fahrion et al 1999).
- However, commercial gasifiers must often use suboptimal feed stocks and operating conditions, and the refractory lifetime is often reduced to < 1.5 years (Stiegel et al 2006).
- The expense of refractory replacement in a large-scale gasifier can exceed \$1 M (Stiegel et al 2006).
- One of the most frequently cited R&D needs is improvement of fundamental understanding of refractory alloy degradation mechanism.







REFRACTORY ALLOYS AND SLAG COMPOSITION

- Majority of reported refractory alloys utilized in a slagging coal gasifier are chromia (Cr₂O₃) and alumina (Al₂O₃) based refractories.
- Chrome oxide materials showed low chemical solubility in gasifier slags by forming high melting spinels/solid solutions with iron oxides (Bennett 2007 and Kim et al 2008).
- In the past, non-chromia refractory compositions did not show comparable performance to high chrome oxide refractory materials.
- Only a few materials (ZrO₂ etc.) have the potential to resist slag corrosion as good as chrome oxide.

	Datong ash	Chromia refractory
SiO ₂	55.2	8.3
Al ₂ O ₃	19.0	24.6
Fe ₂ O ₃	15.4	0.7
CaO	6.2	1.8
Cr ₂ O ₃	-	52.7
ZrO ₂	-	9.4
MgO	1.0	0.4
MnO	0.3	-
Na ₂ O	0.5	1.0
K ₂ O	1.4	-
TiO ₂	0.8	1.8
P ₂ O ₅	0.2	-
SUM	100	99.9

Compon	Wt	Component	Wt%
ent	%	SiO ₂	47
	70	Al_2O_3	25
	92	Fe_2O_3	17
	52	CaO	6
	17	MgO	1
$A_2 O_3$	4./	Na ₂ O	1
	22	TiO ₂	1
$P_2 U_5$	5.5	K ₂ O	2

- Refractories and ash (wt %), Kim et al 2008
- Refractories and ash, Besmann 2008





- Slagging coal gasifier typically operates at high temperature (1300–1600 C) and pressure (2–3 MPa) conditions (Williford et al 2008).
- Industrial refractories have a finite amount of porosity, including initial flaws and joints between bricks.
- These defects are responsible for penetration of the slag into the interior of the refractory by permeation and infiltration mechanisms assisted by the pressure gradients within the gasifier, along with capillary and diffusive intrusion mechanisms.
- The thermal-chemical-mechanical interactions between the refractory and slag result in degradation by corrosion, erosion, cracking, and spalling.





- Slag penetration and chemical corrosion are the primary causes for refractory degradation in a gasifier (Bennett, et al., 2007 and Kim et al. 2008).
- Dominant reaction product at the slag/refractory interface (Fe,Cr)₃O₄ is formed as a result of the following reaction:

 Fe_2O_3 (slag) + Cr_2O_3 (refractory) \rightarrow (Fe,Cr)₃O₄ (R1)

- Once Fe in the slag is depleted, Al_2O_3 in the slag interacted with Cr_2O_3 : Al_2O_3 (slag) + Cr_2O_3 (refractory) \rightarrow (Cr, Al)₂O₃ (R2)
- It was found that the densified large Cr₂O₃ grains were less affected by the reaction (R2) than the Cr₂O₃ small particles observed in the refractory alloys before the tests.





OVERALL PROJECT OBJECTIVES



- The overall objectives of the proposed project are:
 - Develop computational capabilities for predictive analysis of grain boundary interactions using large-scale ReaxFF-Molecular Dynamics (MD) simulations
 - Assess degradation mechanisms, and
 - Design approach to limit segregation at the grain boundaries of refractories for coal gasification and related processes





APPROACH







MULTISCALE MODELING FRAMEWORK



REAXFF REACTIVE FORCE FIELD METHODOLOGY







REAXFF FORCE FIELD DEVELOPMENT







ALLOY MODELING FROM FIRST PRINCIPLES

Method: Plane-wave Basis Density Functional Theory (DFT)

- All calculations were performed using VASP 5
- 0 K electronic structures were calculated by solving the Kohn-Sham equation using plane-wave basis set.



• Structures were optimized by decoupling the quantum representation of electrons from the classical representation of nuclei (Born-Oppenheimer approximation).

More calculation details:

- Projector-augmented-wave (PAW) method for ion-electron potential
- Perdew-Burke-Ernzerhof (PBE) exchange correlation functional
- Plane-wave cut off energy of 400 eV (standard for oxides and sulfides)
- Interval in momentum space for k-point sampling: 0.20 Å⁻¹ 0.25 Å⁻¹
- Spin polarization considered for all calculations





DFT+U STRUCTURE-ENERGY APPROACH

- DFT is capable of producing reasonably accurate predictions for electronic and structural properties of many materials systems
- Traditional DFT with simple delocalized exchange-correlation functional from LDA or GGA does not properly describe partially filled d- or f-orbital electron configurations
- For example, DFT predictions for iron oxide and chromium oxide were found to be off by about 100 kcal/mol
- A cost-effective approaches to take the strong correlation effect into account is DFT+U method
- Idea is to add an explicit correction to the localized electronic states by including the on-site Coulomb interaction of the semi-core level such as d- or forbital
- In such an approach, a multi-orbital mean-field Hubbard-type potential called the U-potential is added to the original density functional Hamiltonian





ENTHALPIES OF FORMATION FOR FeOx AND CrOx

- DFT+U structure-energy calculations for FeOx and CrOx systems were performed in this project
- Enthalpy of formation based on DFT+U formalism with varying the effective U potential in range of 0-8 eV for iron oxide structures and 0-4 eV for chromium oxide structures were obtained



Calculated enthalpies of formation for iron oxide crystals

Calculated enthalpy of formation calculated for chromium oxide crystals





EFFECTIVE U POTENTIAL FOR FeOx AND CrOx

• To determine the effective U potential which would give the best predictions for oxide crystals we formulated a simple optimization function:

$$\lambda (U_{\text{eff}}) = \left[\Delta_{\text{err}}^{\text{X1}} (U_{\text{eff}}) \right]^2 + \left[\Delta_{\text{err}}^{\text{X2}} (U_{\text{eff}}) \right]^2 + \left[\Delta_{\text{err}}^{\text{X3}} (U_{\text{eff}}) \right]^2$$

Here,

$\Delta_{ m err}^{ m X}$	 Difference between theoretical and experimental enthalpies of formation for crystal X 	:
X1, X2, and X3	 FeO, Fe₂O₃, F₃O₄ for iron oxide, and CrO. Cr₂O₂, Cr₂O₄ for chromium oxide 	
U _{eff}	 Effective U potential which minimizes the optimization function (3.6 eV for iron oxide and 2.0 eV for chromium oxide) 	l

 Determined U_{eff} potentials value were applied to all DFT (+U) calculations to produce EOS data for the Fe-O/Cr-O binary systems as well as the Fe-Cr-O ternary systems.





HEAT OF FORMATION FOR AL/CR-ALLOYS

- Al/Cr alloys improve the high-temperature oxidation resistance and mechanical properties
- For example, small amount of AlCr₂ in Al matrix can improve the corrosion resistance and hardness
- ReaxFF was trained against the QM for various Al/Cr (e.g., Al4₅Cr₇, Al₈Cr₅, B₂-AlCr and MoSi₂ type AlCr₂)
- The Al/Cr bond and van der Waals parameters were tarined against the energy-volume relationship over a wide range of volume
- Heats of formation for the Al/Cr phases were well reproduced in ReaxFF





REAXFF FORCE FIELD DEVELOPMENT FOR Cr-O/S/Fe

- The force field was directly derived from QM including 1) EOS for various oxide phases of Cr/O, e.g., Cr(II)-, Cr(III)-, 1) **OM** Cr(IV)- and Cr(II,III)-oxide, 2) 20 S-insertion/substitution into Δ_fH/atom, kcal/mol CrO Cr₃O bcc-Cr and 3) S-binding CrO -20 energies on Cr(100, 110). (Cr-surface energies, -60**Mulliken charges and** 10 density, g/cm Fe/Cr_2O_3 system were also added to the training set (data not shown).
 - Sulfur occupying Cr-site is more stable than the interstitial sulfur.
 - The formation of Fe/Cr binary alloys at low Cr-conc. is favorable, while it is not at high Cr-conc.





REAXFF MOLECULAR DYNAMIC MODELING







- Sulfur is a common impurity in metal alloys
- It tends to segregate to the grain boundaries leading to the grain boundary embrittlement
- Structures for FCC Al and α-Al₂O₃ with grain boundaries and Al-S substitutional defects were created
- To represent random orientation of realistic grain structures, each grain was rotated from the original direction by 0, π/8, π/4, and 3π/8 (in radian) in xy-plane
- The z-direction of the crystal corresponded to (001) direction for FCC Al and (0001) direction for α-Al₂O₃
- 1 at% of sulfur defects were introduced to the grain structure by randomly assigning Al-S substitutional defects to the grain structures with given defect concentrations







SULFUR DIFFUSION AND SEGREGATION IN FCC AI AND α -Al₂O₃ (CONT.)



- Large-scale ReaxFF-MC/MD calculations were performed for constructed FCC Al and α-Al₂O₃ structures
 - S tends to segregate, especially at the boundaries, in a good agreement with the literature trends
- Snapshot obtained after 100 MC/MD stages demonstrates that several grain boundaries are dissolved due to the segregation of S in small clusters
- In contrast, the simulations performed for α -Al₂O₃ demonstrated the absence of substantial S diffusion and segregation
- According to thermodynamics it is nearly impossible to replace oxygen – metal bonds by sulfur – metal bonds
- Also, there is no free space at an intact α -Al₂O₃ lattice for segregation of the big negatively charged sulfur







COMPARISON OF AI-OXIDE VS. AI-SULFIDE GROWTH



Oxidation results in a dense oxide, sulfide growth gives a low-density interface
Oxidation is significantly more exothermic than sulfide growth





PROTECTIVE OXIDE LAYER FORMATION IN AI-BASED ALLOYS

- Oxide scale nucleation starts with the growth of less stable alumina phase (dominantly θ-Al₂O₃)
- ReaxFF-MD/MC calculations were used to understand the mechanism of oxide nucleation on NiAl
- Separation between aluminum-rich and nickel-rich regions begins as early as about 10 ps
- After about 50 ps, a thin aluminum oxide film with a small fraction of nickel oxide clusters is formed







PROTECTIVE OXIDE LAYER FORMATION IN AI-BASED ALLOYS (CONT.)

- There are noticeable differences when SO₂ is introduced to the same oxidation environment
- First, rate of overall oxidation becomes noticeably slower and the resulting depth of oxygen penetration differs by over two atomic layers after 50 ps
- Second, there is not as distinctive separation between the nickel-rich and the aluminum-rich region in the oxidized surface area compared to the oxygen-only case
- Such difference is attributed to the strong S-O bond in SO₂ molecules even after SO₂ surface adsorption
- Unlike the O-O bond in O₂ which almost immediately dissociates on a metal surface, S-O bond in SO₂ hardly dissociates and eventually blocks the diffusion pathway of nearby oxygen atoms as well as Ni and Al atoms drifting to the surface
- As such, the rate of initial penetration by oxygen atoms in the slab surface is significantly slowed down by adsorbed SO₂ atoms
- At the same time, the atomic diffusion of Ni and Al atoms are also slowed down so that the effective phase separation between nickel oxide and aluminum oxide is inhibited
 0.1 ps







SIMULATIONS ON PYRITE OXIDATION AT T=1500K TOWARDS COAL COMBUSTION



 $\begin{array}{l} \textbf{Fe-Al-O fragments}: Fe_7S_{11}O_9, Fe_3S_8O_6, Fe_{19}S_{58}O_{47}, Fe_{34}S_{37}O_{51}, Fe_{24}S_{48}O_{50}, \\ Fe_9S_{13}O_{22}, FeS_3O_3, Fe_2S_5O_6, FeS_6O_2, FeS_2O_5, SO \end{array}$

- Pyrite is an important inorganic component of coal materials
- We can now simulate both the organic and inorganic coal components
- Next step complete coal (silicates/pyrite/organic) combustion







Castro and van Duin Comb.Flame 2013



- 20,000 atoms, LAMMPS/ReaxFF, 4 processors
- Water assists in the crack propagation by transforming the oxide into a weaker hydroxide
- Water front trails after the crack related to high strain rate





WATER EFFECT ON CRACK PROPAGATION IN A AI-OXIDE/AI-METAL INTERFACE



- 20,000 atoms, LAMMPS/ReaxFF, 4 processors





MODELING DEGRADATION AT Cr₂O₃(REFRACTORY)/FeO_x(SLAG)



Reactive MD simulation of refractory/slag interface at high temperature (2000 K)

- ReaxFF force field developed for Fe-Cr-O ternary systems were used to model the refractory/slag interface
- Nucleation and/or growth of any Fe-Cr-O complexes at the interface would indicate the degradation of refractory surface by the slag phase:



CONCLUSIONS







CONCLUSIONS

- ReaxFF potentials for Cr/Fe/Al/O/S interactions relevant to many industrially important alloys (i.e., steels, refractory alloys) were developed
- First-principles energetics data from QM calculations were used to evaluate the ReaxFF parameters
- QM calculations were performed using DFT+U approach applicable to systems with partially filled d- or f-orbital electron configurations
- Oxidation energies for different iron oxide crystals (Fe, Fe₂O₃, and Fe₃O₄) and chromium oxide crystals (CrO₂, Cr₂O₃, and Cr₃O₄) were analyzed to find the proper +U correction potentials
- Developed ReaxFF potentials for Cr-Fe alloy are reliable to the scale of 3 kcal/mol per atom for energy formation and correctly describe the thermodynamics of various structures





CONCLUSIONS (CONT.)

- Developed force fields were used to provide substantive insights to many important research questions
- Analysis of diffusion dynamics of Al adatoms on BCC Fe and Fe/O surface revealed that exchange diffusion is more favored for the Fe/O surface than for the Fe surface
- Modeling NiAl alloy surface oxidation demonstrated important role of sulfur surface segregation
- Rate of oxidation became noticeably slower and the resulting depth of oxygen penetration differed by over two atomic layers after 50 ps of simulations with and without SO₂
- This was attributed to the strong S-O bond in SO₂ molecules
- Large-scale ReaxFF-MC/MD calculations demonstrated the dissolving of grain boundaries due to sulfur segregation in FCC Al
- In contrast, the absence of substantial S diffusion and segregation for $\alpha\text{-Al}_2\text{O}_3\,$ was demonstrated





PUBLISHED/ACCEPTED PEER-REVIEW PUBLICATIONS

- 1. A. Vasenkov, D. Newsome, O. Verners, M. F. Russo, R. Zaharieva, and A. C. T. van Duin, *Reactive Molecular Dynamics study of Mo-based systems under high pressure conditions*, J. Appl. Phys. 112, 013511 (2012)
- 2. H. Kwak, Y. Shin, A.C.T. van Duin, and A. Vasenkov, *Ab initio multiscale modeling of alloy surface segregation*, J. Phys.: Condense Matter, 24, 48 (2012)
- 3. Y. Shin, H. Kwak, C. Zou, A.V. Vasenkov, A.C.T. van Duin, *Development and validation* of a ReaxFF reactive force field for Fe/Al/Ni alloys: molecular dynamics study of elastic constants, diffusion and segregation, J. Phys. Chem. A, 116, 12163-74 (2012)
- 4. Y. Shin, T. Shan, T. Liang, M.J. Noordhoek, S.B. Sinnott, A.C.T. van Duin and S.R. Phillpot, *Variable charge many-body interatomic potentials*, MRS Bull, 37, pp504-512 (2012)
- 5. T. Liang, Y. Shin, Y. Cheng, D.E. Yilmaz, K.G. Vishnu, O. Verners, C. Zou, S.R. Phillpot, S.B. Sinnott and A.C.T. van Duin, *Reactive Potentials for Advanced Atomistic Simulations*, Annu. Rev. Mater. Res., 43 (2013)
- 6. B. S. Jeon, Q. van Overmeere, Adri C. T. van Duin, and S. Ramanathan, *Nanoscale Q1 Q2 oxidation and complex oxide growth on single crystal iron surfaces and external electric field effects*, Phys. Chem. Chem. Phys., accepted for publication



